

HFA30PB120

Ultrafast, Soft Recovery Diode

Features

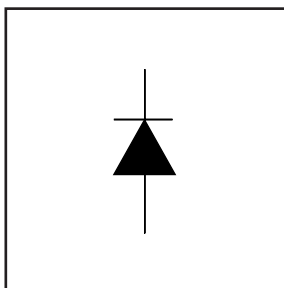
- Ultrafast Recovery
- Ultrasoft Recovery
- Very Low I_{RRM}
- Very Low Q_{rr}
- Guaranteed Avalanche
- Specified at Operating Conditions

Benefits

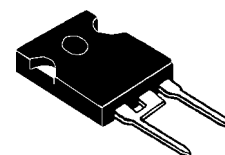
- Reduced RFI and EMI
- Reduced Power Loss in Diode and Switching Transistor
- Higher Frequency Operation
- Reduced Snubbing
- Reduced Parts Count

Description

International Rectifier's HFA30PB120 is a state of the art ultra fast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 1200 volts and 30 amps continuous current, the HFA30PB120 is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultra fast recovery time, the HEXFRED product line features extremely low values of peak recovery current (I_{RRM}) and does not exhibit any tendency to "snap-off" during the t_b portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED HFA30PB120 is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.



$V_R = 1200V$
$V_F(\text{typ.})^* = 2.4V$
$I_{F(AV)} = 30A$
$Q_{rr}(\text{typ.}) = 490nC$
$I_{RRM}(\text{typ.}) = 8.1A$
$t_{rr}(\text{typ.}) = 37ns$
$di_{(rec)M}/dt(\text{typ.})^* = 130A/\mu s$



**TO-247AC
(Modified)**

Absolute Maximum Ratings

	Parameter	Max.	Units
V_R	Cathode-to-Anode Voltage	1200	V
$I_F @ T_C = 25^\circ C$	Continuous Forward Current		A
$I_F @ T_C = 100^\circ C$	Continuous Forward Current	30	
I_{FSM}	Single Pulse Forward Current	120	
I_{FRM}	Maximum Repetitive Forward Current	90	
$P_D @ T_C = 25^\circ C$	Maximum Power Dissipation		W
$P_D @ T_C = 100^\circ C$	Maximum Power Dissipation		
T_J T_{STG}	Operating Junction and Storage Temperature Range	-55 to +150	$^\circ C$

* 125°C

HFA30PB120

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Electrical Characteristics @ $T_J = 25^\circ\text{C}$ (unless otherwise specified)

	Parameter	Min.	Typ.	Max.	Units	Test Conditions
V_{BR}	Cathode Anode Breakdown Voltage	1200	—	—	V	$I_R = 100\mu\text{A}$
V_{FM}	Max Forward Voltage	—	2.5	3.0	V	$I_F = 16\text{A}$
		—	3.2	3.93		$I_F = 32\text{A}$ See Fig. 1
		—	2.3	2.7		$I_F = 16\text{A}, T_J = 125^\circ\text{C}$
I_{RM}	Max Reverse Leakage Current	—	0.75	20	μA	$V_R = V_R \text{ Rated}$ See Fig. 2
		—	375	2000		$T_J = 125^\circ\text{C}, V_R = 0.8 \times V_R \text{ Rated}$
C_T	Junction Capacitance	—	27	40	pF	$V_R = 200\text{V}$ See Fig. 3
L_S	Series Inductance	—	8.0	—	nH	Measured lead to lead 5mm from package body

Dynamic Recovery Characteristics @ $T_J = 25^\circ\text{C}$ (unless otherwise specified)

	Parameter	Min.	Typ.	Max.	Units	Test Conditions
t_{rr}	Reverse Recovery Time	—	30	—	ns	$I_F = 1.0\text{A}, di/dt = 200\text{A}/\mu\text{s}, V_R = 30\text{V}$
t_{rr1}	See Fig. 5, 10	—	90	135		$T_J = 25^\circ\text{C}$
t_{rr2}		—	164	245		$T_J = 125^\circ\text{C}$
I_{RRM1}	Peak Recovery Current See Fig. 6	—	5.8	10	A	$T_J = 25^\circ\text{C}$
I_{RRM2}		—	8.3	15		$T_J = 125^\circ\text{C}$
Q_{rr1}	Reverse Recovery Charge See Fig. 7	—	260	675	nC	$T_J = 25^\circ\text{C}$
Q_{rr2}		—	680	1838		$T_J = 125^\circ\text{C}$
$di_{(rec)M}/dt1$	Peak Rate of Fall of Recovery Current	—	120	—	A/ μs	$T_J = 25^\circ\text{C}$
$di_{(rec)M}/dt2$	During t_b See Fig. 8	—	76	—		$T_J = 125^\circ\text{C}$

Thermal - Mechanical Characteristics

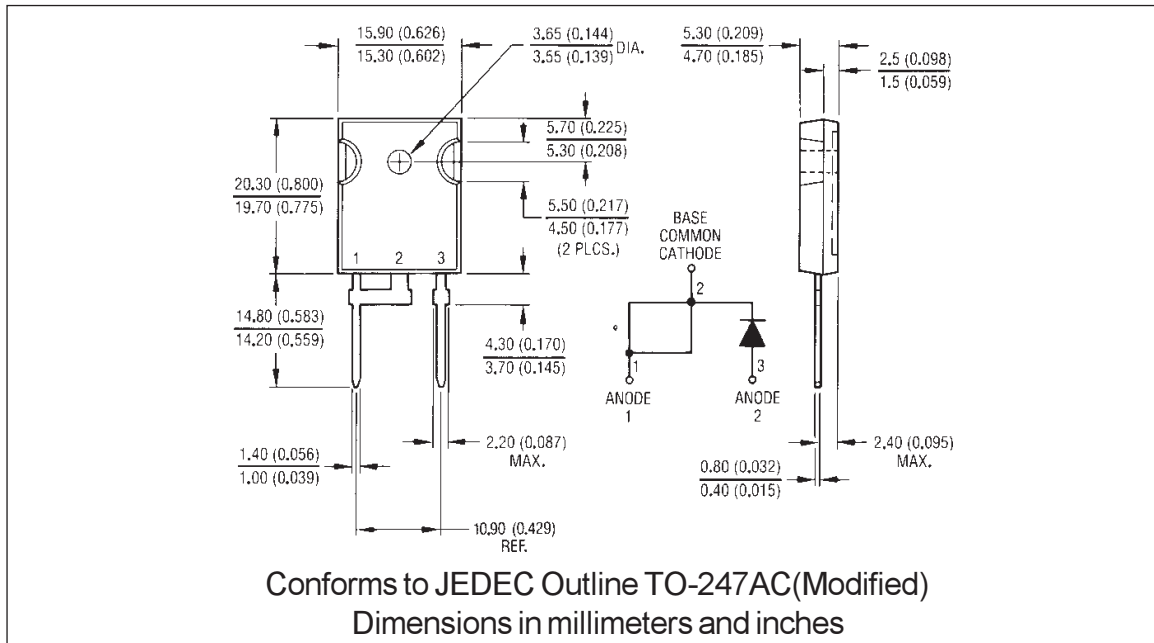
	Parameter	Min.	Typ.	Max.	Units
$T_{\text{lead}}^{(2)}$	Lead Temperature	—	—	300	$^\circ\text{C}$
$R_{\theta JC}$	Thermal Resistance, Junction to Case	—	—	0.83	K/W
$R_{\theta JA}^{(3)}$	Thermal Resistance, Junction to Ambient	—	—	80	
$R_{\theta CS}^{(4)}$	Thermal Resistance, Case to Heat Sink	—	0.50	—	
Wt	Weight	—	2.0	—	g
		—	0.07	—	(oz)
	Mounting Torque	6.0	—	12	Kg-cm
		5.0	—	10	lbf-in

- ① $L=100\mu\text{H}$, duty cycle limited by max T_J
 ② 0.063 in. from Case (1.6mm) for 10 sec
 ③ Typical Socket Mount
 ④ Mounting Surface, Flat, Smooth and Greased

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Data and specifications subject to change without notice.

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